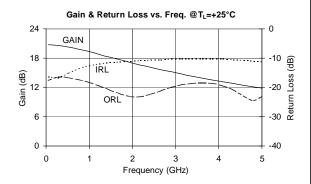


Product Description

Stanford Microdevices' SGA-2463 is a high performance SiGe Heterojunction Bipolar Transistor MMIC Amplifier. A Darlington configuration featuring 1 micron emitters provides high $F_{\scriptscriptstyle T}$ and excellent thermal perfomance. The heterojunction increases breakdown voltage and minimizes leakage current between junctions. Cancellation of emitter junction non-linearities results in higher suppression of intermodulation products. At 850 Mhz and 20mA , the SGA-2463 typically provides +20.1 dBm output IP3, 19.6 dB of gain, and +8 dBm of 1dB compressed power using a single positive voltage supply. Only 2 DC-blocking capacitors, a bias resistor and an optional RF choke are required for operation.



SGA-2463

DC-2000 MHz, Cascadable SiGe HBT MMIC Amplifier



Product Features

- · High Gain: 17.1 dB at 1950 MHz
- Cascadable 50 Ohm
- Patented SiGe Technology
- Operates From Single Supply
- Low Thermal Resistance Package

Applications

- Cellular, PCS, CDPD
- Wireless Data, SONET
- Satellite

| Symbol | Parameter | Units | Frequency | Min. | Тур. | Max. |
|------------------|--|------------|---------------------|------|--------------|------|
| G | Small Signal Gain | dB dB | 850 MHz 1950 MHz | 17.6 | 19.6 17.1 | 21.6 |
| P _{1dB} | Output Power at 1dB Compression | dBm dBm | 850 MHz 1950 MHz | | 8.0 6.6 | |
| OIP ₃ | Output Third Order Intercept Point (Power out per tone = -10dBm) | dBm dBm | 850 MHz 1950 MHz | | 20.1 19.5 | |
| Bandwidth | Determined by Return Loss (<-10dB) | MHz | | | 2000 | |
| IRL | Input Return Loss | dB | 1950 MHz | | 11.1 | |
| ORL | Output Return Loss | dB | 1950 MHz | | 23.1 | |
| NF | Noise Figure | dB | 1950 MHz | | 3.1 | |
| V _D | Device Voltage | V | | 2.3 | 2.6 | 2.9 |
| R _{Th} | Thermal Resistance | °C/W | | | 255 | |

Test Conditions:

 $V_s = 5 V$

= 120 Ohms

 $I_D = 20 \text{ mA Typ.}$

OIP₃ Tone Spacing = 1 MHz, Pout per tone = -10 dBm Z₂ = Z₃ = 50 Ohms

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SGA-2463 DC-2000 MHz Cascadable MMIC Amplifier

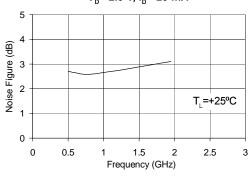
Typical RF Performance at Key Operating Frequencies

| ter l | Unit | 400 | | | | | |
|------------------|---------------|--|---|------------------------------|---|---|--|
| | | 100 | 500 | 850 | 1950 | 2400 | 3500 |
| | dB | | 20.3 | 19.6 | 17.1 | | |
| ntercept Point d | dBm | | 19.7 | 20.1 | 19.5 | | |
| 3 Compression d | dBm | | 8.1 | 8.0 | 6.6 | | |
| | dB | 16.7 | 15.3 | 13.2 | 11.1 | 10.8 | 10.3 |
| | dB | 17.2 | 16.6 | 17.7 | 23.1 | 22.4 | 18.6 |
| | dB | 23.7 | 23.1 | 23.2 | 22.9 | 22.5 | 21.0 |
| | dB | | 2.7 | 2.6 | 3.1 | | |
| _ | B Compression | Intercept Point dBm B Compression dBm dB dB dB | Intercept Point dBm B Compression dBm dB 16.7 dB 17.2 dB 23.7 | Intercept Point dBm 19.7 | Intercept Point dBm 19.7 20.1 B Compression dBm 8.1 8.0 dB 16.7 15.3 13.2 dB 17.2 16.6 17.7 dB 23.7 23.1 23.2 | Intercept Point dBm 19.7 20.1 19.5 B Compression dBm 8.1 8.0 6.6 dB 16.7 15.3 13.2 11.1 dB 17.2 16.6 17.7 23.1 dB 23.7 23.1 23.2 22.9 | Intercept Point dBm 19.7 20.1 19.5 B Compression dBm 8.1 8.0 6.6 dB 16.7 15.3 13.2 11.1 10.8 dB 17.2 16.6 17.7 23.1 22.4 dB 23.7 23.1 23.2 22.9 22.5 |

Test Conditions:

 $V_s = 5 V$ $R_{sus} = 120 Ohms$ I_D = 20 mA Typ. T_. = 25°C OIP₃ Tone Spacing = 1 MHz, Pout per tone = -10 dBm $Z_0 = Z_1 = 50$ Ohms

Noise Figure vs. Frequency $V_p = 2.6 \text{ V}, I_p = 20 \text{ mA}$



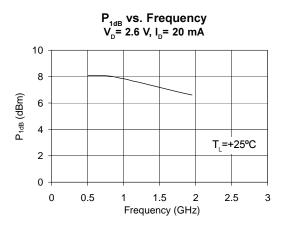
OIP₃ vs. Frequency V_p= 2.6 V, I_p= 20 mA 30 25 15 10 0 0.5 1 1.5 2 2.5 3 Frequency (GHz)

Absolute Maximum Ratings

| Parameter | Absolute Limit | |
|---|----------------|--|
| Max. Device Current (I _D) | 40 mA | |
| Max. Device Voltage (V _D) | 4 V | |
| Max. RF Input Power | -2 dBm | |
| Max. Junction Temp. (T _J) | +150°C | |
| Operating Temp. Range (T _L) | -40°C to +85°C | |
| Max. Storage Temp. | +125°C | |

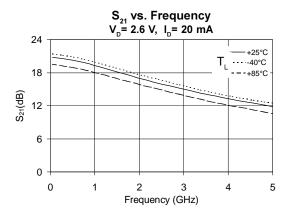
Operation of this device beyond any one of these limits may cause permanent damage.

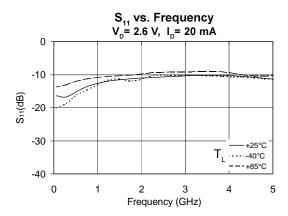
Bias Conditions should also satisfy the following expression: I_DV_D (max) < $(T_J - T_L)/R_{th}$

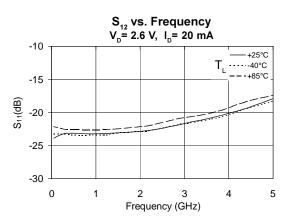


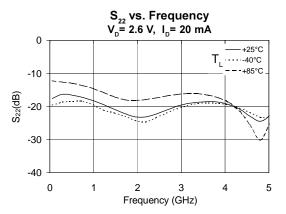


SGA-2463 DC-2000 MHz Cascadable MMIC Amplifier



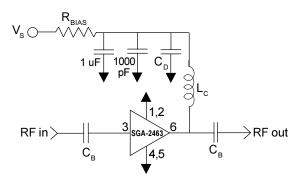


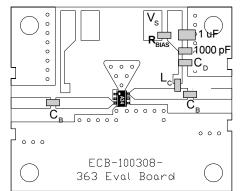






SGA-2463 Basic Application Circuit





Part Identification Marking

The part will be marked with an "A24" designator on the top surface of the package.



For package dimensions, refer to outline drawing at www.stanfordmicro.com



Application Circuit Element Values

| Reference | | Frequency (Mhz) | | | | | |
|----------------|--------|-----------------|-------|-------|-------|--|--|
| Designator | 500 | 850 | 1950 | 2400 | 3500 | | |
| C _B | 220 pF | 100 pF | 68 pF | 56 pF | 39 pF | | |
| C _D | 100 pF | 68 pF | 22 pF | 22 pF | 15 pF | | |
| L _c | 68 nH | 33 nH | 22 nH | 18 nH | 15 nH | | |

| Recommended Bias | s Resist | or Value | s for I _D = | =20mA |
|--|----------|----------|------------------------|-------|
| Supply Voltage(V _s) | 5 V | 8 V | 10 V | 12 V |
| R _{BIAS} | 120 Ω | 270 Ω | 360 Ω | 470 Ω |
| Note: R _{BIAS} provides DC bias stability over temperature. | | | | |

Mounting Instructions

- 1. Use a large ground pad area near device pins 1, 2, 4, and 5 with many plated through-holes as shown.
- We recommend 1 or 2 ounce copper. Measurements for this data sheet were made on a 31 mil thick FR-4 board with 1 ounce copper on both sides.

| Pin # | Function | Description |
|-------|-----------------|---|
| 3 | RF IN | RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation. |
| 1 | GND | Connection to ground. Use via holes for best performance to reduce lead inductance as close to ground leads as possible. |
| 6 | RF OUT/ BIAS | RF output and bias pin. DC voltage is present on this pin, therefore a DC blocking capacitor is necessary for proper operation. |
| 2,4,5 | GND | Sames as Pin 2 |

Part Number Ordering Information

| Part Number | Reel Size | Devices/Reel |
|-------------|-----------|--------------|
| SGA-2463 | 7" | 3000 |